

DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION

DOCKET NO. TS01-1132

As a below named Inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name;

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled Complementary Metal Oxide Semiconductor Transistor Technology Using Selective Epitaxy Of A Strained Silicon Germanium Layer

the specification of which (check one)			
X is attached hereto			
was filed on			
Application Serial No.			
and was amended on(if	ossilvoble)		
I hereby state that I have reviewed and amended by any amendment referred to	understand the contents of the at	pove Identified specification including the	e claims, as
Title 37. Code of Federal Regulations,	§1.56(a)	examination of this application in accord	
having a filing date before that of the a		de §119 of any foreign application(s) for reign application for patent or inventor's aimed:	r patent or certificate
Prior Foreign Application(s)		Prionty Claimed:	
(Number)	(Country)	(Day/Month/Year Filed)	
(Number)	(Country)	(Day/Month/Year Filed)	
I hereby claim the benefit under Title 3 as the subject matter of each of the cla manner provided by the first paragraph information as defined in Title 37, Cocapplication and the national or PCT in	35. United States Code §120 of a ims of this application is not disc of Title 35. United States Code le of Federal Regulations, §1.56 ternational filing date of this app	ny United States application(s) listed bel closed in the prior United States applicati , §112, I acknowledge the duty to disclos (a) which occurred between the filing dat lication:	ow and, insofar on in the le material le of the prior
(Application Serial No.)	(Filing Date) (Status)	(patented, pending, abandoned)	
I hereby declare that all statements ma belief are believed to be true; and furth the like so made are punishable by fine and that such willful false statements r	de herein of my own knowledge her that these statements were ma e or imprisonment, or both, unde may jeopardize the validity of the	are true and that all statements made on ade with the knowledge that willful false or Section 1001 of Title 18 of the United application or any patent issued thereon	information and statements and States Code i.
POWER OF ATTORNEY: As a name application and transact all business in	ed inventor, I hereby appoint the the Patent and Trademark Office	following attorney(s) and/or agent(s) to jue connected therewith. (list name & regi	prosecute this stration no.)
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